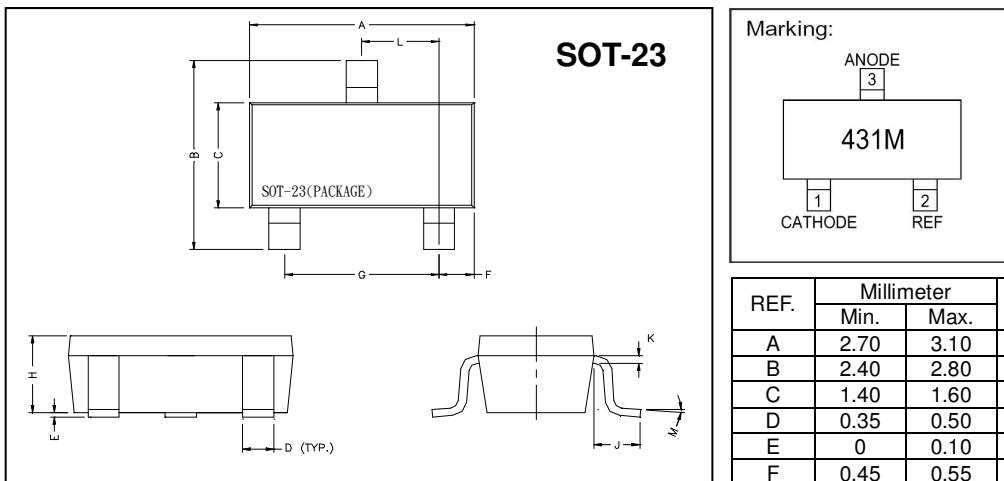


G431M Adjustable Shunt Regulator**Description**

The G431M series are three-terminal adjustable regulators with guaranteed thermal stability over applicable temperature ranges. The output voltage may be set to any value between VREF (approximately 2.495v) and 36v with two external resistors. It provides very wide applications, including shunt regulator, series regulator, switching regulator, voltage reference and others.

Package Dimensions

REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	1.90	REF.
B	2.40	2.80	H	1.00	1.30
C	1.40	1.60	K	0.10	0.20
D	0.35	0.50	J	0.40	-
E	0	0.10	L	0.85	1.15
F	0.45	0.55	M	0°	10°

Absolute Maximum Ratings at Ta = 25°C

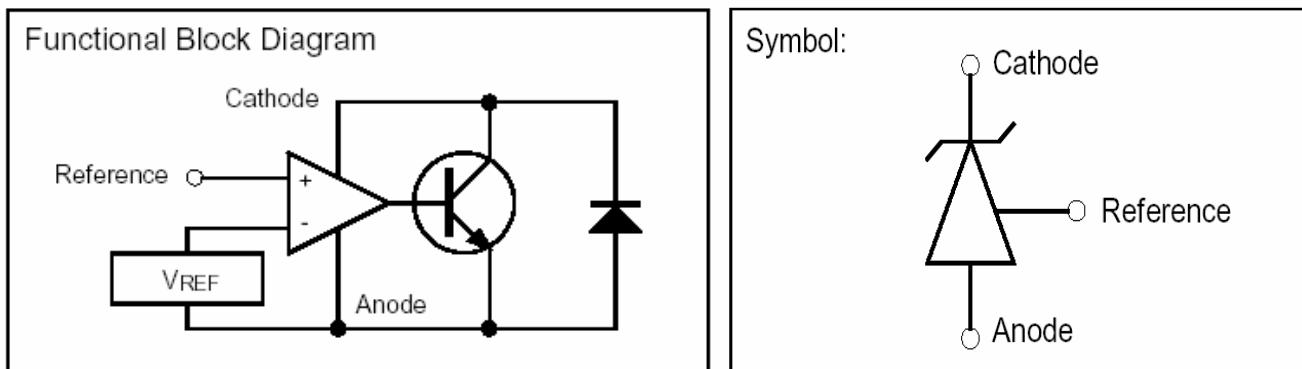
Parameter	Symbol	Ratings			Unit
Junction Temperature	T _j	+150			°C
Storage Temperature	T _{stg}	-65 ~ +150			°C
Cathode Voltage	V _{KA}	37			V
Cathode Current Range(Continuous)	I _{KA}	-100~+150			mA
Reference Input Current Range	I _{REF}	-0.05~+10			mA
Total Power Dissipation	PD	225			mW

Characteristics at Ta = 25°C

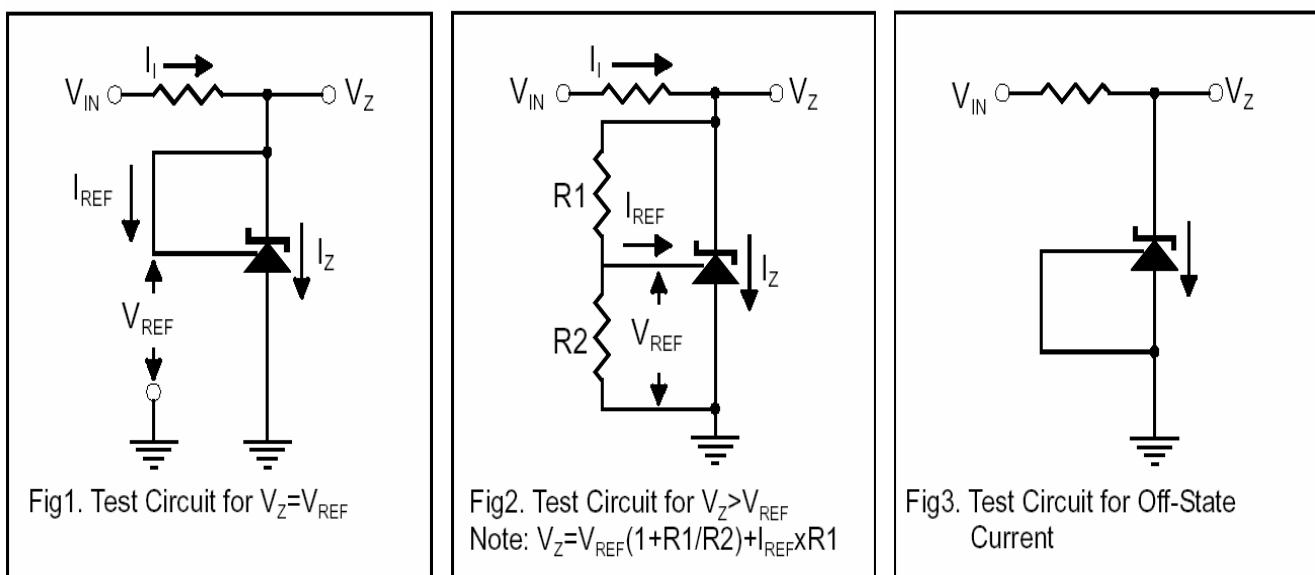
Parameter	Symbol	Min	Typ.	Max.	Unit	Test Conditions	
Cathode Voltage	V _{KA}	V _{REF}	-	36	V		
Cathode Current	I _{KA}	1	-	100	mA		
Reference Input Voltage G431MC	V _{REF}	2.445	2.495	2.545	V	V _{KA} = V _{REF} , I _K =10mA	
G431MB		2.470	2.495	2.520			
G431MA		2.483	2.495	2.507			
Deviation of reference Input Voltage Over temperature(note)	ΔV _{REF} /ΔT	-	4.5	17	mV	V _{KA} =V _{REF} , I _K =10mA T _{min} ≤Ta≤T _{max}	
Ratio of Change in Reference Input Voltage to the Change in Cathode Voltage	ΔV _{REF} /ΔV _{KA}	-	-1.0	-2.7	mV/V	I _K =10mA	ΔV _{KA} =10V~V _{REF}
		-	-0.5	-2.0			ΔV _{KA} =36V~10V
Reference Input Current	I _{REF}	-	1.5	4	uA	I _K =10mA, R ₁ =10KΩ, R ₂ =∞	
Deviation of reference Input Current Over Full Temperature Range	ΔI _{REF} /ΔT	-	0.4	1.2	uA	I _K =10mA, R ₁ =10KΩ, R ₂ =∞ TA=Full Temperature	
Minimum Cathode Current for Regulation	I _{KA(min)}	-	0.45	1.0	mA	V _{KA} =V _{REF}	
Off-State Cathode Current	I _{KA(off)}	-	0.05	1.0	uA	V _{KA} =36V, V _{REF} =0	
Dynamic Impedance	Z _{KA}	-	0.15	0.5	Ω	V _{KA} =V _{REF} , I _K =1 to 100mA, f≤1.0KHz	

Note: T_{min}= 0°C, T_{max}=+70°C

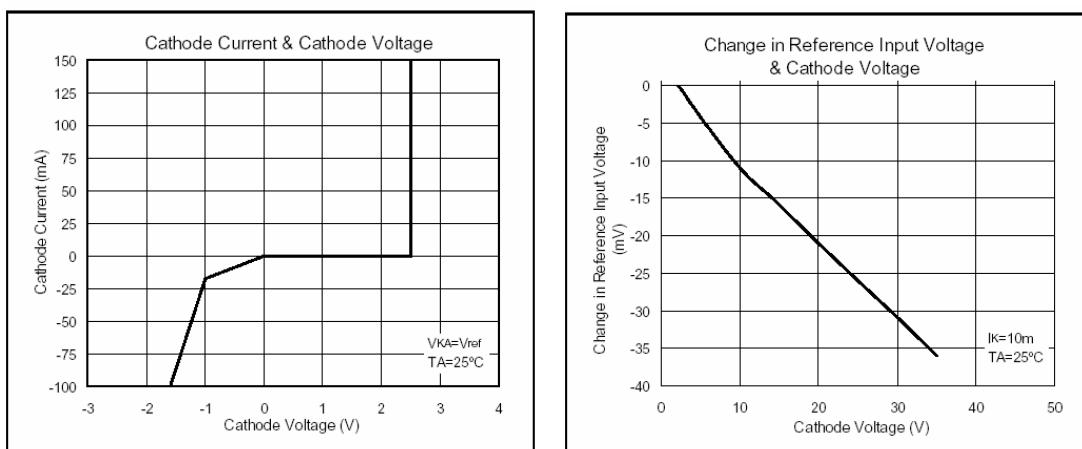
Functional Block Diagram & Symbol

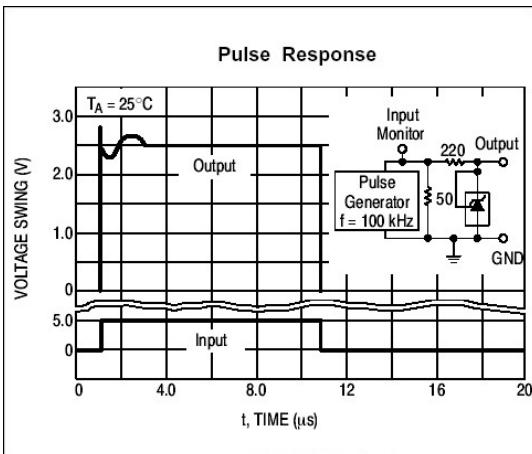
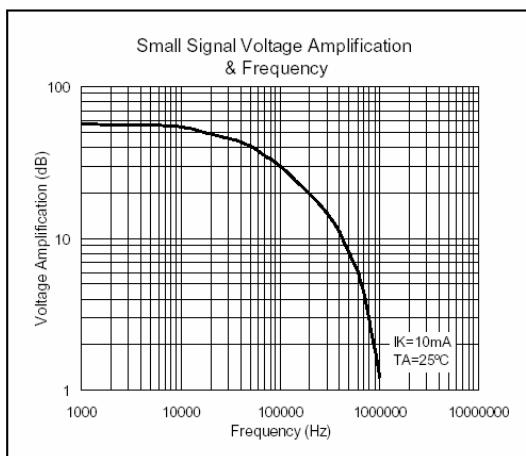
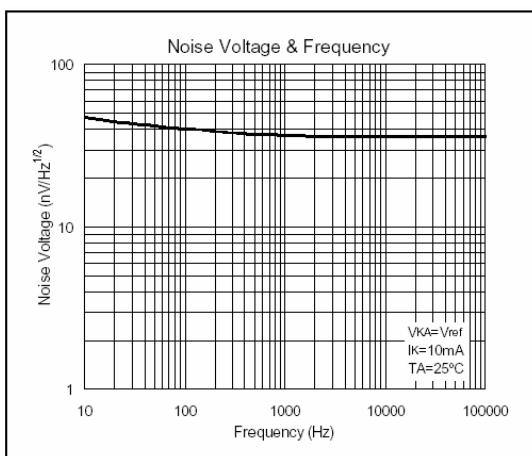
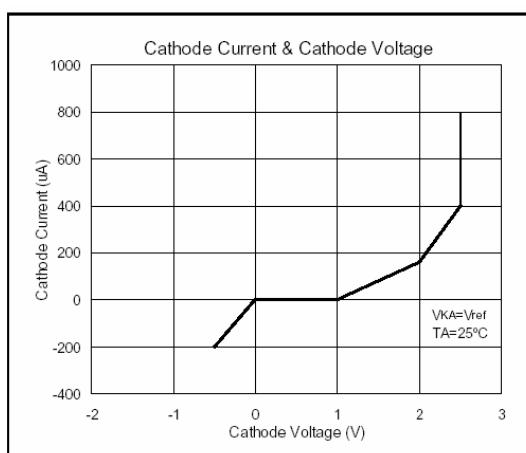
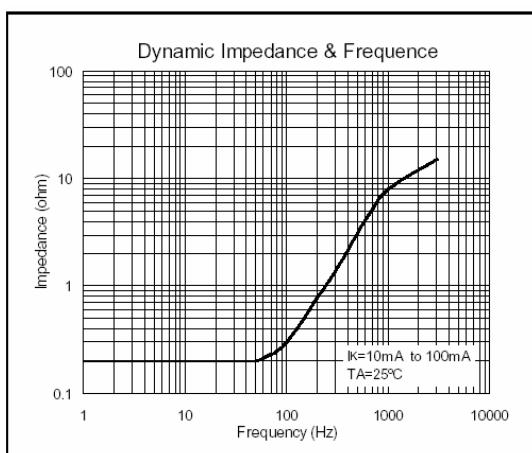


Test Circuits



Characteristics Curve





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Head Office And Factory:

- Taiwan:** No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
TEL : 886-3-597-7061 FAX : 886-3-597-9220, 597-0785
- China:** (201203) No.255, Jang-Jiang Tsai-Lueng RD. , Pu-Dung-Hsin District, Shang-Hai City, China
TEL : 86-21-5895-7671 ~ 4 FAX : 86-21-38950165